

HiPerFRED

V_{RRM} = 400 V
 I_{FAV} = 10 A
 t_{rr} = 45 ns

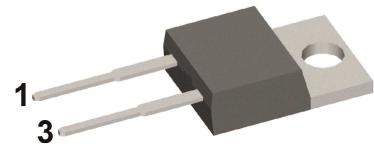
High Performance Fast Recovery Diode

Low Loss and Soft Recovery

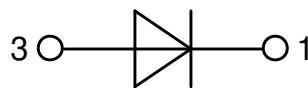
Single Diode

Part number

DPG10I400PA



Backside: cathode



Features / Advantages:

- Planar passivated chips
- Very low leakage current
- Very short recovery time
- Improved thermal behaviour
- Very low I_{rm} -values
- Very soft recovery behaviour
- Avalanche voltage rated for reliable operation
- Soft reverse recovery for low EMI/RFI
- Low I_{rm} reduces:
 - Power dissipation within the diode
 - Turn-on loss in the commutating switch

Applications:

- Antiparallel diode for high frequency switching devices
- Antisaturation diode
- Snubber diode
- Free wheeling diode
- Rectifiers in switch mode power supplies (SMPS)
- Uninterruptible power supplies (UPS)

Package: TO-220

- Industry standard outline
- RoHS compliant
- Epoxy meets UL 94V-0

Disclaimer Notice

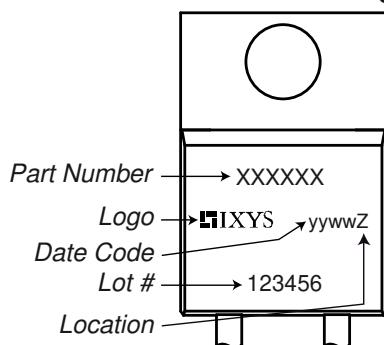
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Fast Diode

Symbol	Definition	Conditions	Ratings			
			min.	typ.	max.	
V_{RSM}	max. non-repetitive reverse blocking voltage	$T_{VJ} = 25^\circ\text{C}$			400	V
V_{RRM}	max. repetitive reverse blocking voltage	$T_{VJ} = 25^\circ\text{C}$			400	V
I_R	reverse current, drain current	$V_R = 400 \text{ V}$ $V_R = 400 \text{ V}$	$T_{VJ} = 25^\circ\text{C}$ $T_{VJ} = 150^\circ\text{C}$		1 0.15	μA mA
V_F	forward voltage drop	$I_F = 10 \text{ A}$ $I_F = 20 \text{ A}$ $I_F = 10 \text{ A}$ $I_F = 20 \text{ A}$	$T_{VJ} = 25^\circ\text{C}$ $T_{VJ} = 150^\circ\text{C}$		1.32 1.51 1.03 1.24	V V V V
I_{FAV}	average forward current	$T_C = 150^\circ\text{C}$ rectangular $d = 0.5$	$T_{VJ} = 175^\circ\text{C}$		10	A
V_{F0} r_F	threshold voltage slope resistance } for power loss calculation only		$T_{VJ} = 175^\circ\text{C}$		0.77 19.8	V $\text{m}\Omega$
R_{thJC}	thermal resistance junction to case				2.3	K/W
R_{thCH}	thermal resistance case to heatsink			0.5		K/W
P_{tot}	total power dissipation		$T_C = 25^\circ\text{C}$		65	W
I_{FSM}	max. forward surge current	$t = 10 \text{ ms}; (50 \text{ Hz}), \text{sine}; V_R = 0 \text{ V}$	$T_{VJ} = 45^\circ\text{C}$		150	A
C_J	junction capacitance	$V_R = 200 \text{ V}$ $f = 1 \text{ MHz}$	$T_{VJ} = 25^\circ\text{C}$		12	pF
I_{RM}	max. reverse recovery current		$T_{VJ} = 25^\circ\text{C}$ $T_{VJ} = 125^\circ\text{C}$		4 6	A A
t_{rr}	reverse recovery time	$I_F = 10 \text{ A}; V_R = 270 \text{ V}$ $-di_F/dt = 200 \text{ A}/\mu\text{s}$	$T_{VJ} = 25^\circ\text{C}$ $T_{VJ} = 125^\circ\text{C}$		45 65	ns ns

Package TO-220

Symbol	Definition	Conditions	Ratings			
			min.	typ.	max.	
I_{RMS}	RMS current	per terminal			35	A
T_{VJ}	virtual junction temperature		-55		175	°C
T_{op}	operation temperature		-55		150	°C
T_{stg}	storage temperature		-55		150	°C
Weight				2		g
M_d	mounting torque		0.4		0.6	Nm
F_c	mounting force with clip		20		60	N

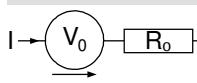
Product Marking

Part description

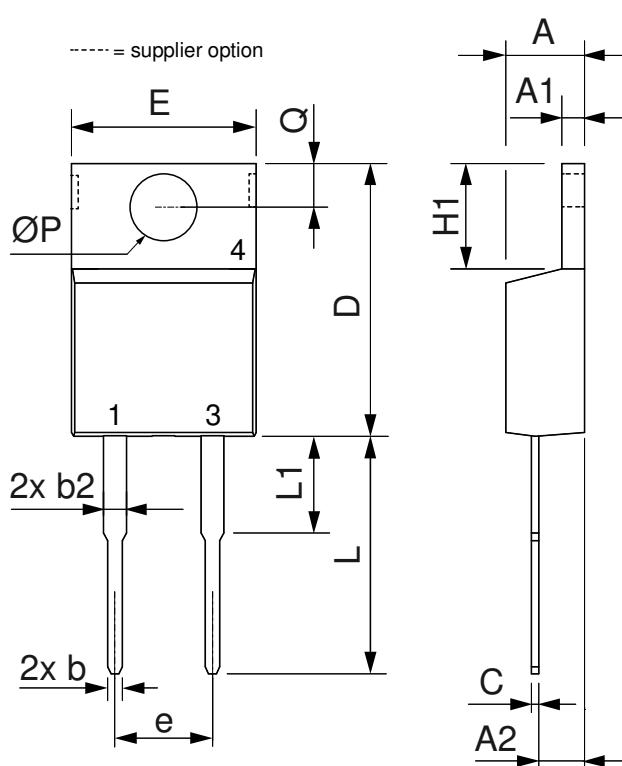
D = Diode
P = HiPerFRED
G = extreme fast
10 = Current Rating [A]
I = Single Diode
400 = Reverse Voltage [V]
PA = TO-220AC (2)

Ordering	Ordering Number	Marking on Product	Delivery Mode	Quantity	Code No.
Standard	DPG10I400PA	DPG10I400PA	Tube	50	506654

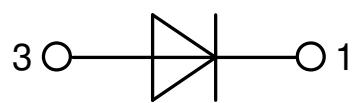
Similar Part	Package	Voltage class
DPG10I400PM	TO-220ACFP (2)	400

Equivalent Circuits for Simulation
** on die level*
 $T_{VJ} = 175^\circ\text{C}$

	Fast Diode	
$V_{0\ max}$	threshold voltage	0.77
$R_{0\ max}$	slope resistance *	16.6

Outlines TO-220


Dim.	Millimeter		Inches	
	Min.	Max.	Min.	Max.
A	4.32	4.82	0.170	0.190
A1	1.14	1.39	0.045	0.055
A2	2.29	2.79	0.090	0.110
b	0.64	1.01	0.025	0.040
b2	1.15	1.65	0.045	0.065
C	0.35	0.56	0.014	0.022
D	14.73	16.00	0.580	0.630
E	9.91	10.66	0.390	0.420
e	5.08	BSC	0.200	BSC
H1	5.85	6.85	0.230	0.270
L	12.70	13.97	0.500	0.550
L1	2.79	5.84	0.110	0.230
ØP	3.54	4.08	0.139	0.161
Q	2.54	3.18	0.100	0.125



Fast Diode

